



Atty. Docket No. RBS2.P049

PATENT

IN THE UNITED STATES PATENT OFFICE

In Re Patent Application of

First Named Inventor: Ware, Frederick A.

Application No.: 10/053,340

Filed: 10/22/2001

For: METHOD AND APPARATUS FOR SIGNALING
BETWEEN DEVICES OF A MEMORY SYSTEM

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Examiner: Nguyen, Than Vinh

Art Unit: 2187

Confirmation No. 8663

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Sir:

Enclosed is an Information Disclosure Citation Form 1449/PTO together with a copy of each reference cited therein, excluding U.S. Patents and Published U.S. Patent Applications. It is respectfully requested that the cited references be considered and that the enclosed copy of the Form 1449/PTO be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant.

This Information Disclosure Statement is being submitted pursuant to 37 CFR 1.97(b)(4). No fee is believed to be due.

Pursuant to 37 CFR 1.97(h), the submission of this Information Disclosure Statement is not to be construed as an admission that the information cited in this statement is material to patentability.

The Commissioner is hereby authorized to charge any fee deficiency in connection with this submission to Deposit Account No. 501914.

Respectfully submitted,

SHEMWELL MAHAMEDI LLP

Date Jan 26, 2007

Charles E. Shemwell
Charles E. Shemwell, Reg. No. 40,171
Tel. 408-236-6645

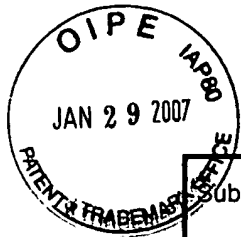


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	Examiner	Nguyen, Than Vinh
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U.S. Patent Documents					
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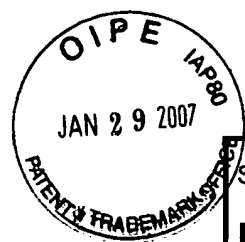


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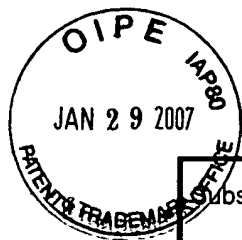


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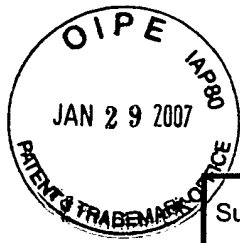


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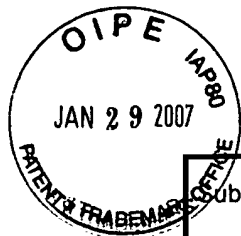
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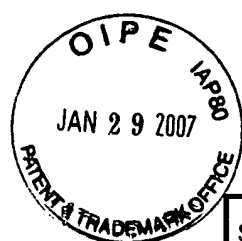
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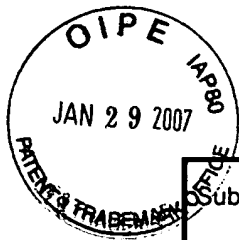


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